TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

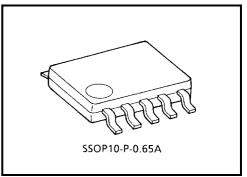
TA6038FN

Shock Sensor IC

 $\rm TA6038FN$ detects an existence of external shock through the shock sensor and output.

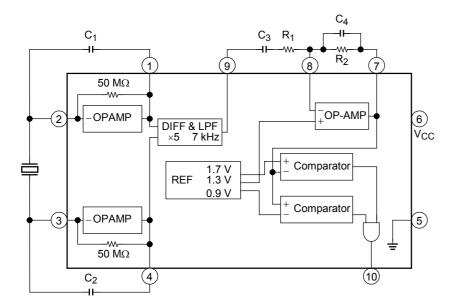
Features

- TA6038FN operates from 2.7 to 5.5 V DC single power supply voltage.
- Signal from the shock sensor is amplified according to setting gain, and is detected through the internal window comparator.
- TA6038FN incorporates 1-ch shock detecting circuitry.
- Input terminal of sensor signal is designed high impedance. Differential input impedance = $100 \text{ M}\Omega$ (typ.)
- LPF (low pass filter) circuitry is incorporated. Cut-off frequency of LPF = 7 kHz
- Sensitivity of shock detection can be adjusted by external devices.
- Small package SSOP10-P-0.65A (0.65 mm pitch)

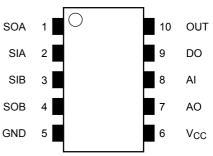


Weight: 0.04 g (typ.)

Block Diagram



Pin Connection (top view)



Pin Function

Pin No.	Pin Name	Function
1	SOA	Amp (A) output terminal
2	SIA	Connection terminal of shock sensor
3	SIB	Connection terminal of shock sensor
4	SOB	Amp (B) output terminal
5	GND	Ground terminal
6	V _{CC}	Power supply voltage
7	AO	Op-Amp output terminal
8	AI	Op-Amp input terminal
9	DO	Differential-Amp output terminal
10	OUT	Output terminal (output = "L" when shock is detected.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	7	V
Power dissipation	PD	300	mW
Storage temperature	T _{stg}	-55 to 150	°C

Recommend Operating Condition

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	2.7 to 5.5	V
Operating temperature	T _{opr}	-25 to 85	°C

Note: The IC may be destroyed due to short circuit between adjacent pins, incorrect orientation of device's mounting, connecting positive and negative power supply pins wrong way round, air contamination fault, or fault by improper grounding.

Electrical Characteristics (unless otherwise specified, $V_{CC} = 3.3 V$, Ta = 25°C)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Supply voltage	V _{CC}		_	2.7	3.3	5.5	V
Supply ourrent	Icc	(1)	V _{CC} = 3.3 V	_	1.8	2.5	mA
Supply current			V _{CC} = 5.0 V		1.8	2.5	

(DIFF-AMP)

Characteristics		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Input impedance	(Note 1)	Zin	_	_	30	100	_	MΩ
Gain		GvBuf	(2)	_	13.6	14	14.4	dB
Output DC voltage		VoBuf	(3)	Connect C = 1000 pF between 1 pin and 2 pin, 3 pin and 4 pin	0.7	1	1.3	V
Low pass filter cut-off freq.		fc	(4)	Frequency at –3dB point	5	7	11	kHz
Output source current		IBso	(5)	$Voh = V_{CC} - 1 V$	300	800	_	μA
Output sink current		IBsi	(6)	Vol = 0.3 V	75	130	_	μA

Note 1: Marked parameters are reference data.

(OP-AMP)

Characteristics		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Cut-off frequency	(Note 1)	fT		_	1.5	2		MHz
Openloop gain	(Note 1)	Gvo		_	80	90	_	dB
Input voltage 1		Vin1	(7)	_	1.235	1.3	1.365	V
Input current		l _{in}	(8)	_	_	25	50	nA
Offset voltage	(Note 1)	Voff		_	-5	0	5	mV
Output source current		IAso	(9)	$Voh = V_{CC} - 1 V$	250	800	_	μA
Output sink current		IAsi	(10)	Vol = 0.3 V	130	200		μA

Note 1: Marked parameters are reference data.

(window-comparator)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Trip voltage 1 (Note 1)	Vtrp1	_		Vin1 ±0.38	Vin1 ±0.4	Vin1 ±0.42	V
Output source current	IWso	(11)	$Voh = V_{CC} - 0.5 V$	30	50	_	μA
Output sink current	IWsi	(12)	Vol = 0.3 V	300	800		μA

Note 1: Marked parameters are reference data.

Application Note

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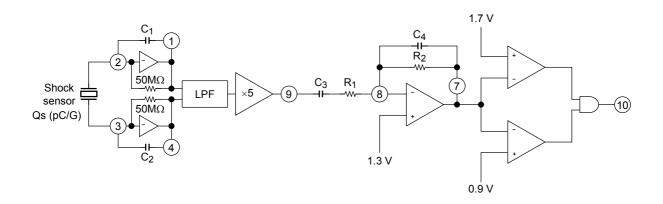


Figure 1 The Configuration of G-Force Sensor Amplifier

Figure 1 shows the configuration of G-Force sensor amplifier. The shock sensor is connected between the pins 2 and 3.

- < How to output 0 or 1 from the pin 10 to detect whether there is a shock or not. > Using a sensor with the sensitivity Qs (pC/G) to detect the shock g (G). -
- a. Setting gain: C1 = C2 (pF), R1 (k Ω), R2 (k Ω)

$$\frac{\text{Qs} \times \text{g}}{\text{C1}} \times 2 \times 5 \times \frac{\text{R2}}{\text{R1}} = 0.4 \text{ (V)}$$
$$\text{C1} = \text{C2} = \frac{\text{Qs} \times \text{g}}{0.04} \times \frac{\text{R2}}{\text{R1}}$$

$$C1 = C2 = \frac{0.34 \times 5}{0.04} \times \frac{100}{10} = 425 \text{ (pF)}$$

b. Setting the frequency (Hz) of HPF: Setting C3 (μ F), R1 (k Ω)

fc (Hz) =
$$\frac{1}{2 \times \pi \times \text{R1} \times \text{C3}} \times 10^3$$

Example: Setting the frequency to 20 Hz with $R1 = 10 (k\Omega)$.

Example: Detecting 5 (G)-shock using a sensor

with Qs = 0.34 (pC/G), R1 = 10 (k Ω), R2 = 100 (k Ω).

C3 =
$$\frac{1}{2 \times \pi \times 10 \times 20} \times 10^3 = 0.8 \,(\mu F)$$

c. Setting the frequency (kHz) of LPF: Setting C4 (pF), R2 (k Ω)

fc (kHz) =
$$\frac{1}{2 \times \pi \times \text{R2} \times \text{C4}} \times 10^6$$

Example: Setting the frequency to 5 kHz with $R2 = 100 (k\Omega)$.

C4 =
$$\frac{1}{2 \times \pi \times 100 \times 5} \times 10^{6} = 318 \,(\text{pF})$$

< How to output the voltage according to the shock through the pin 7. >

– Using a sensor with the sensitivity Qs (pC/G), and assuming the shock sensitivity of the system is Vsystem (mV/G). –

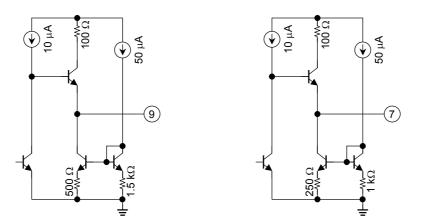
a. Setting gain: C1 = C2 (pF), R1 (k Ω), R2 (k Ω)

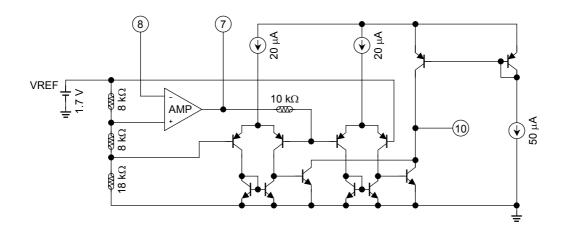
$$\begin{split} & \frac{Qs}{C1} \times 2 \times 5 \times \frac{R2}{R1} = Vsystem \times 10^3 \, (mV/G) \\ & C1 = C2 = \frac{Qs}{Vsystem} \times \frac{R2}{R1} \times 10^4 \, (pF) \end{split}$$

Example: Designing the system with 200 (mV/G) by using a sensor that Qs = 0.34 (pC/G), R1 = 10 (k Ω), R2 = 100 (k Ω).

C1 = C2 =
$$\frac{0.34}{200} \times \frac{100}{10} \times 10^4 = 170 \text{ (pF)}$$

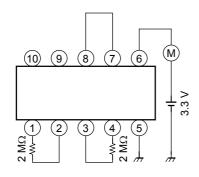
Equivalent Circuit



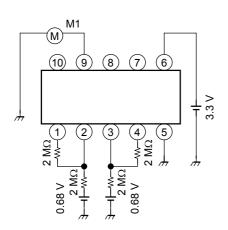


Test Circuit

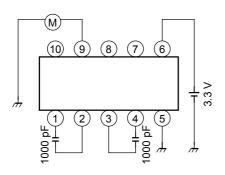
(1) Supply current **ICC**



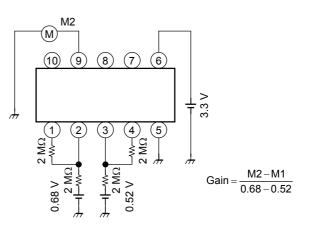
(2) DIFF-AMP Gain **GvBuf** Step 1



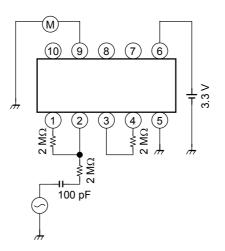
(3) DIFF-AMP Output DC voltage **VoBuf**



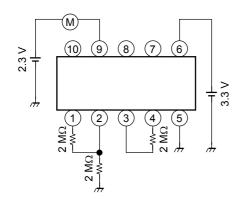
Step 2



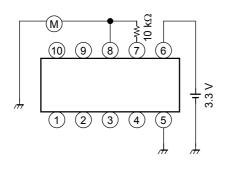
(4) DIFF-AMP Low pass filter cut-off freq. **fc**



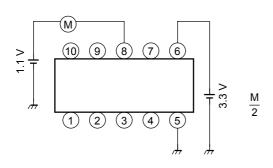
(5) DIFF-AMP Output source current **IBso**



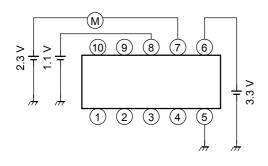
(7) OP-AMPInput voltage 1 Vin1



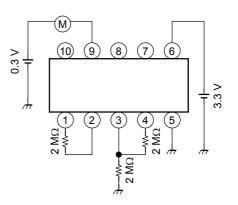
(8) OP-AMP Input current **I**in



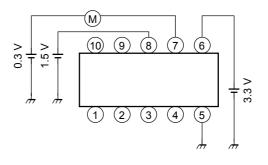
(9) OP-AMP Output source current **IAso**



(6) DIFF-AMP Output sink current **IBsi**

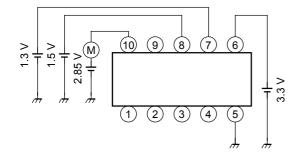


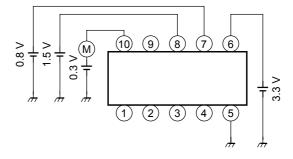
(10) OP-AMP Output sink current **IAsi**





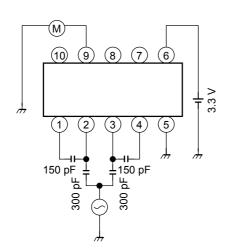
- (11) Window comparator Output source current **IWso**
- (12) Window comparatorOutput sink current **IWsi**



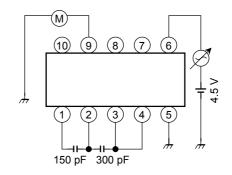


Test Circuit (for reference)

(a) DIFF-AMP CMRR

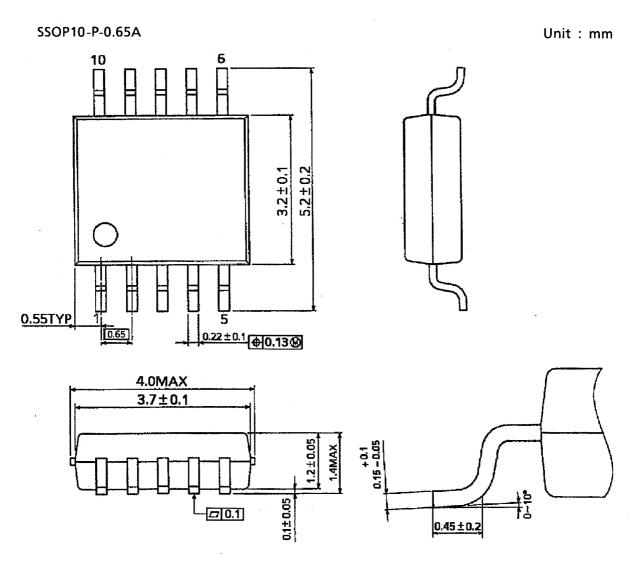


(b) DIFF-AMP **PSRR**



TA6038FN

Package Dimensions



Weight: 0.04 g (typ.)

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Handbook" etc.,

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